



## High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

### Features

- Wide operating temperature range: -40°C to 100°C
- Operating Temperature range: 4.5V to 30V
- Threshold Input Current:  $I_{FLH} = 5 \text{ mA (max)}$
- Common mode transient immunity :  $\pm 10 \text{ kV}/\mu\text{s}$  (min)
- RoHS and REACH Compliance
- MSL class 1
- Regulatory Approvals
  - ✓ UL - UL1577 (E364000)
  - ✓ VDE - EN60747-5-5(VDE0884-5)
  - ✓ CQC – GB4943.1, GB8898(14001104999)
  - ✓ IEC62368 (FI/41119)

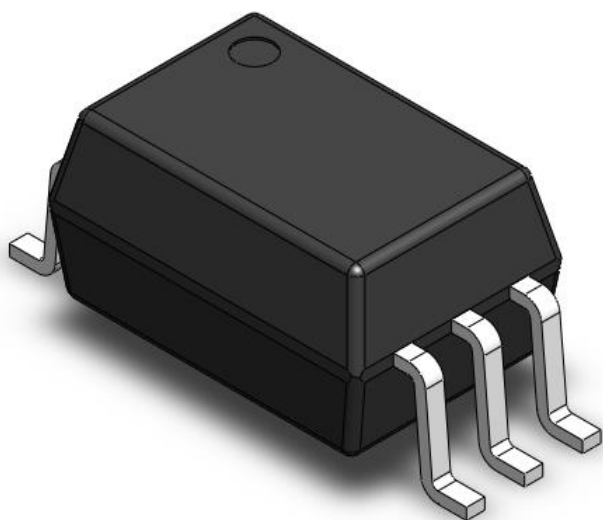
### Description

The CTS480 contains AlGaAs LED and optical detector with power output stage and Schmitt trigger circuit application. The totem pole output eliminates the need for a pull-up resistor and allows for a direct-drive Intelligent Power Module or gate drive. Propagation delay difference between devices has been minimized to maximize inverter efficiency through reduced switching dead time.

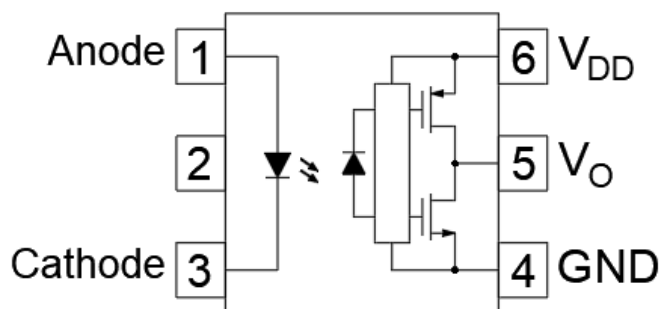
### Applications

- IPM interface isolation
- Isolated IGBT/Power MOSFET gate drive
- Industrial Inverter
- AC brushless and DC motor driver

### Package Outline



### Schematic



#### Truth Table

LED	Output
Off	Low
On	High

Note: Different lead forming options available. See package dimension.



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### Absolute Maximum Ratings $T_A = 25^{\circ}\text{C}$ , unless otherwise specified

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters	Ratings	Units	Notes
V <sub>ISO</sub>	Isolation voltage (AC, 1 minute, 40 ~ 60% R.H.)	5000	V <sub>RMS</sub>	1
T <sub>OPR</sub>	Operating temperature	-40 ~ +100	°C	
T <sub>STG</sub>	Storage temperature	-55 ~ +125	°C	
T <sub>SOL</sub>	Soldering temperature (For 10 seconds)	260	°C	2
P <sub>T</sub>	Total Power Dissipation	185	mW	
<b>Emitter</b>				
I <sub>F</sub>	Forward current	50	mA	
I <sub>FP</sub>	Peak forward current (<1 μs pulse width, 300 pps)	1	A	
V <sub>R</sub>	Reverse voltage	5	V	
<b>Detector</b>				
V <sub>O(PEAK)</sub>	Peak Output Voltage	35	V	3
I <sub>OPH</sub>	Output High Peak Current	50	mA	
V <sub>CC</sub>	Supply voltage	35	V	

#### Notes

1. AC for 1 minute, RH = 40 ~ 60%.
2. For reflow profile 10 second peak.
3. The V<sub>O(PEAK)</sub> voltage CAN NOT BE high than V<sub>CC</sub>.



# CTS480

## High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

### Electrical Characteristics

Over recommended operating conditions  $T_A = -40$  to  $100$  °C. Typical values are measured at  $V_{CC}=30V$ ,  $V_{EE}=GND$ ,  $T_A = 25^\circ C$  (unless otherwise stated)

#### Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$V_F$	Forward voltage	$I_F = 10mA$	-	1.4	1.8	V	
$V_R$	Reverse Voltage	$I_R = 10\mu A$	5.0	-	-	V	
$\Delta V_F / \Delta T_A$	Temperature coefficient of forward voltage	$I_F = 10mA$	-	-1.8	-	mV/°C	

#### Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$I_{CCL}$	Logic Low Supply Current	$I_F = 0mA$ , $V_O = \text{Open}$	--	1.4	3.0	mA	
$I_{CCH}$	Logic High Supply Current	$I_F = 10mA$ , $V_O = \text{Open}$	--	1.4	3.0	mA	

#### Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$V_{OH}$	High Level Output Voltage	$I_F = 10mA$ , $I_{OH} = -6.5mA$	$V_{CC} - 0.5$	$V_{CC} - 0.1$		V	
$V_{OL}$	Low Level Output Voltage	$I_F = 0mA$ , $I_{OL} = 6.5mA$	-	$V_{EE} + 0.1$	$V_{EE} + 0.5$	V	
$I_{OSH}$	High Level Output Current	$I_F = 5 mA$ , $V_{CC} = 5.5 V$ $V_O = GND$	--	--	-80	mA	1
		$I_F = 5 mA$ , $V_{CC} = 20 V$ $V_O = GND$	--	--	-120		1
$I_{OSL}$	Low Level Output Current	$I_F = 0 mA$ , $V_{CC} = V_O = 5.5 V$	80	--	--	mA	1
		$I_F = 0 mA$ , $V_{CC} = V_O = 20 V$	150	--	--		1
$I_{FLH}$	Input Threshold Current	$V_O > 1V$	--	2.6	5.0	mA	
$V_{FLH}$	Input Threshold Voltage	$V_O > 1V$	0.8	--	--	V	

Note 1: Duration of output short circuit time should not exceed 500  $\mu s$ .



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Over recommended operating conditions  $T_A = -40$  to  $100$  °C. Typical values are measured at  $V_{CC}=30V$ ,  $V_{EE}= GND$ ,  $T_A = 25^\circ C$  (unless otherwise stated)

## Switching Characteristics

Symbol	Parameters	Test Conditions		Min	Typ	Max	Units	Notes
$t_{PHL}$	High to Low Propagation Delay	$I_F = 5mA$ , $V_{CC} = 30V$  $f = 100kHz$ , Duty = 10%, $T_A = 25^\circ C$		--	130	250	ns	
$t_{PLH}$	Low to High Propagation Delay			--	180	250	ns	
$P_{WD}$	Pulse Width Distortion			--	--	250	ns	
PDD	Propagation Delay Difference Between Any Two Parts			-100	--	250	ns	
$t_r$	Rise Time			--	20	--	ns	
$t_f$	Fall Time			--	20	--	ns	
CM <sub>H</sub>	Common Mode Transient High	$V_{CC} = 5V$ , $T_A = 25^\circ C$ ,	$I_F = 5mA$	20	--	--	kV/ $\mu s$	
CM <sub>L</sub>	Common Mode Transient Low	$V_{CM} = 1.0kV$	$I_F = 0mA$	20	--	--	kV/ $\mu s$	



# High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

## Typical Characteristic Curves $T_A = 25^\circ\text{C}$ , unless otherwise specified

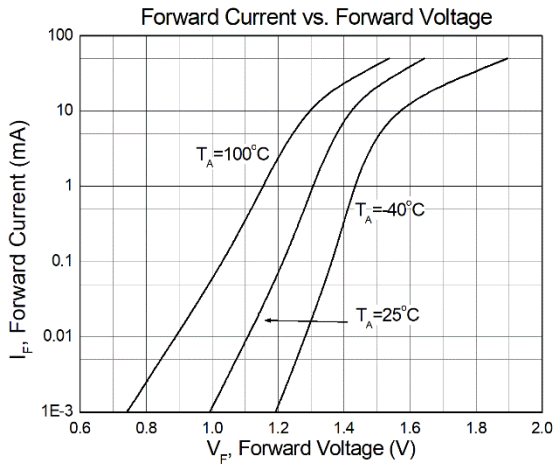


Figure 1

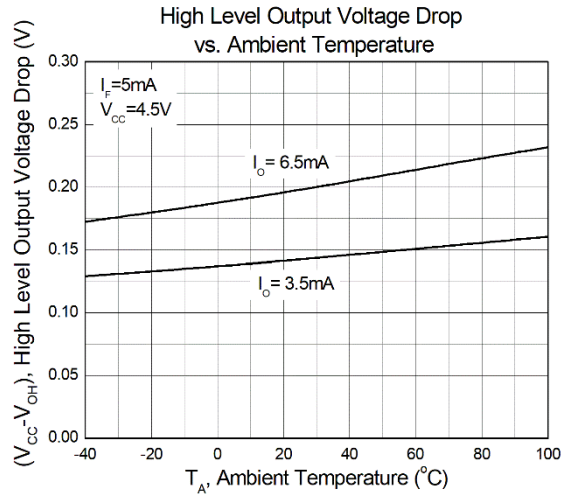


Figure 2

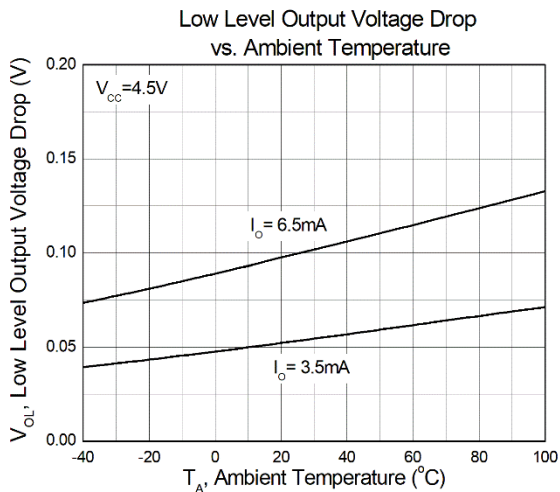


Figure 3

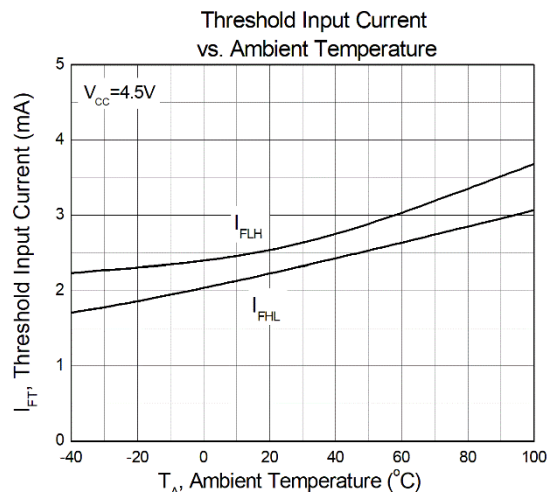


Figure 4

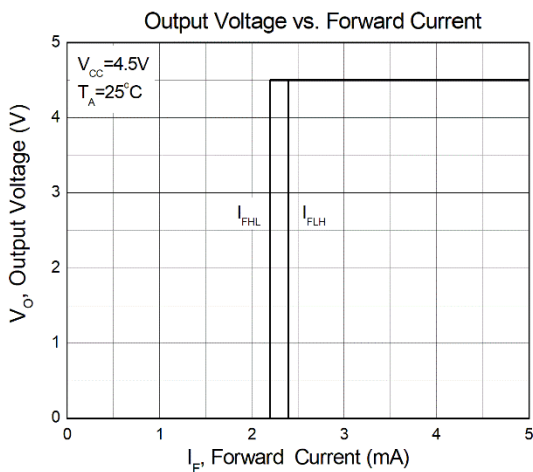


Figure 5

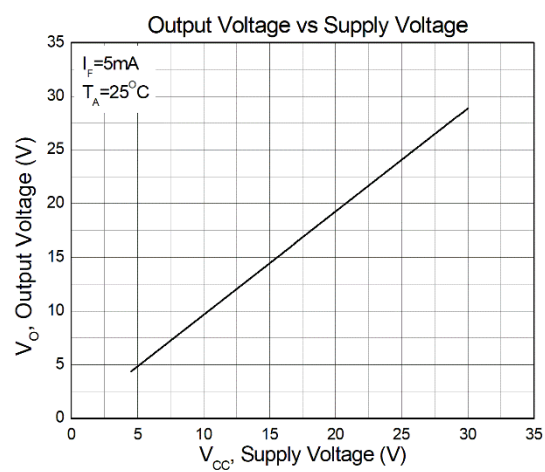


Figure 6



# CTS480 High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

## Typical Characteristic Curves $T_A = 25^\circ\text{C}$ , unless otherwise specified

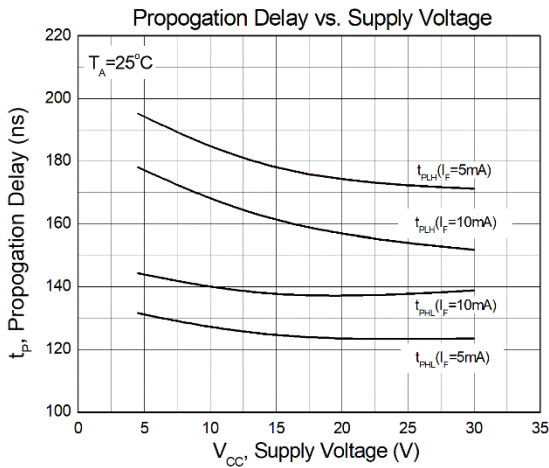


Figure 7

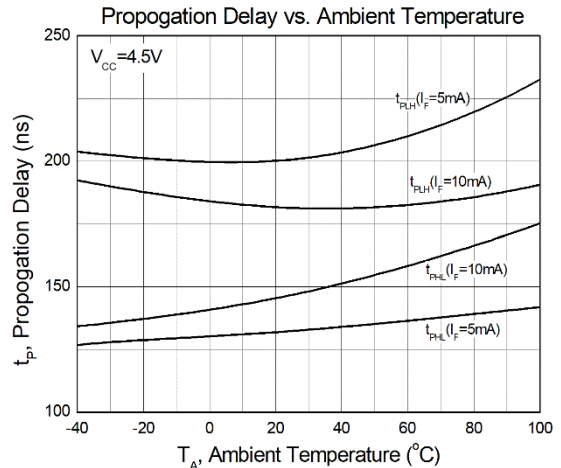


Figure 8

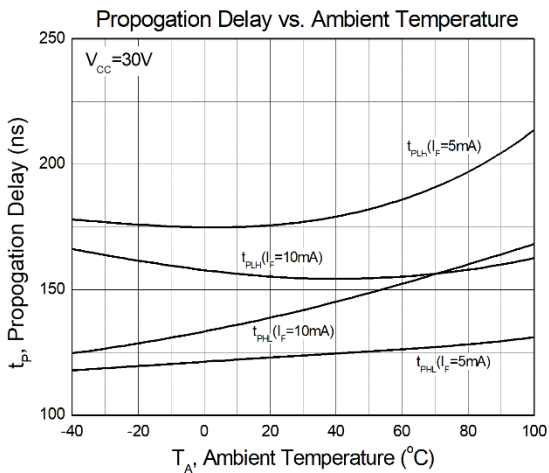


Figure 9

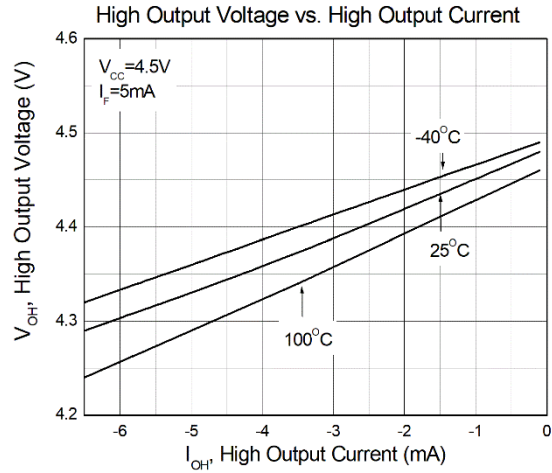


Figure 10

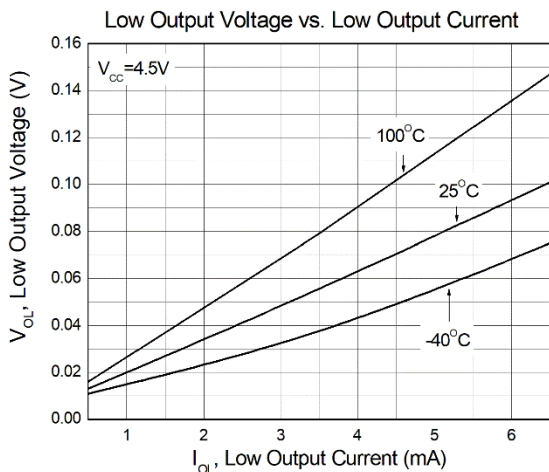


Figure 11



# High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

## Test Circuits

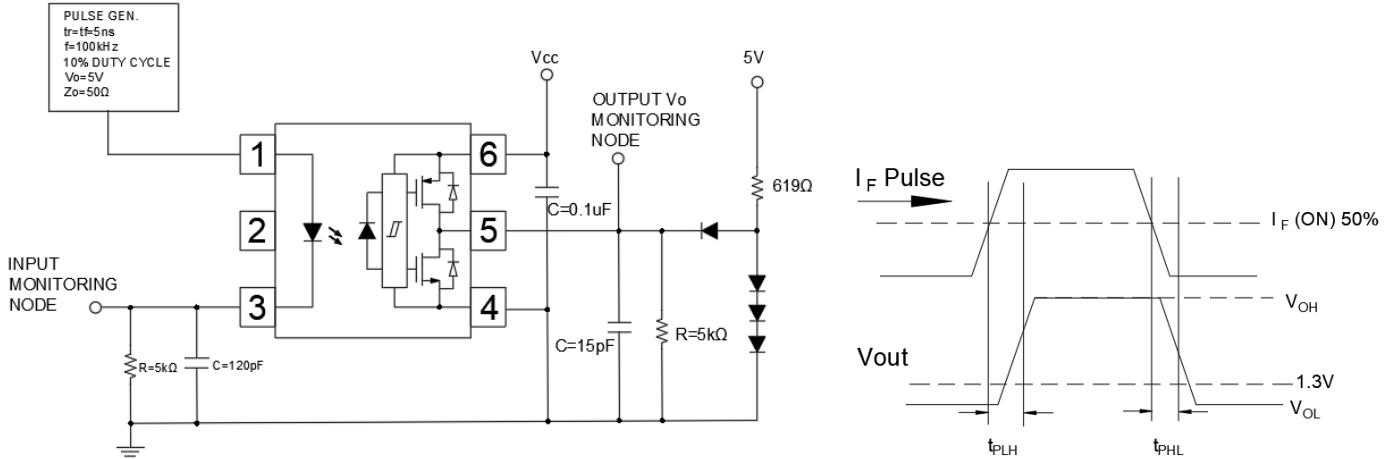


Fig. 10 Test circuit and waveforms for  $t_{PHL}$ ,  $t_{PLH}$ ,  $t_r$ , and  $t_f$

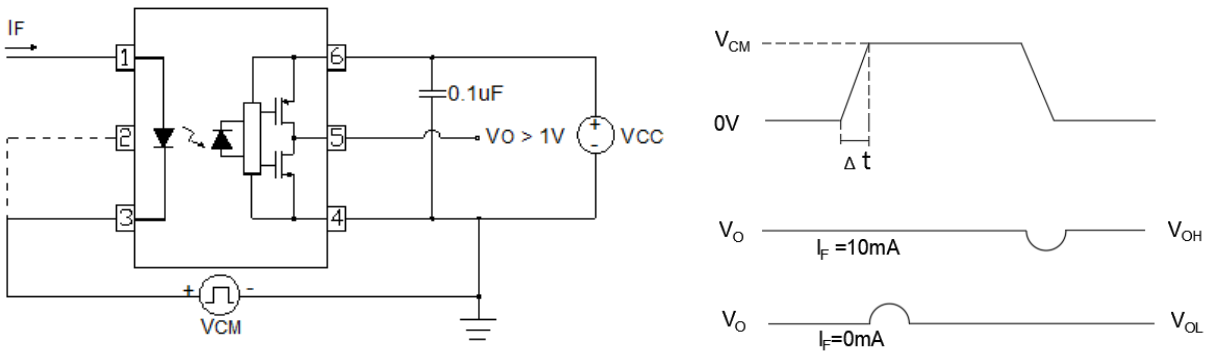


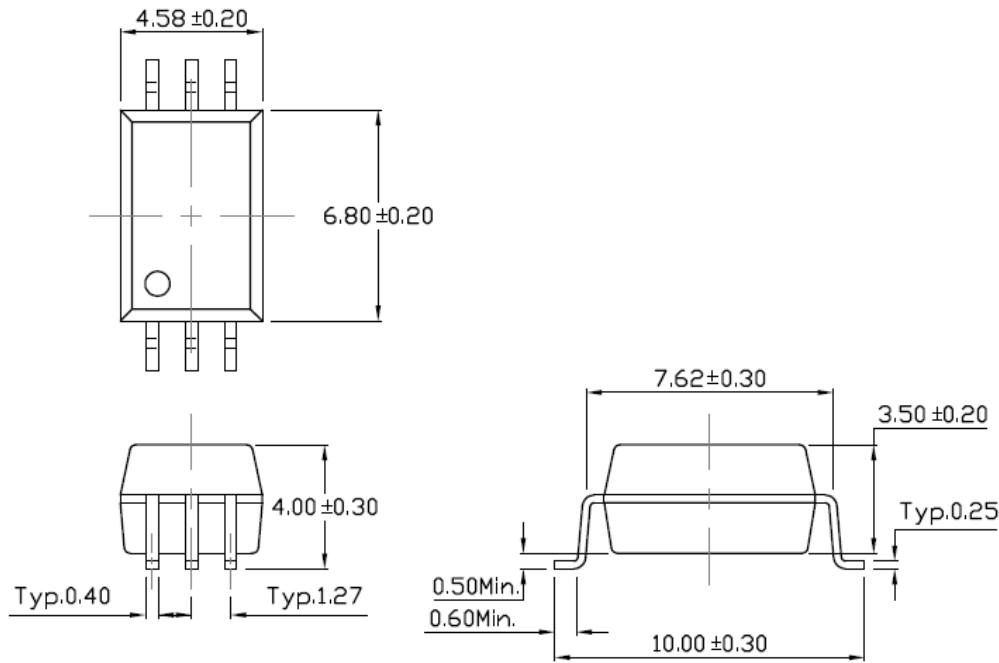
Fig. 11 Test circuit for Common mode Transient Immunity



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## Package Dimension *Dimensions in mm unless otherwise stated*

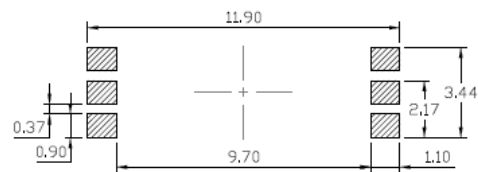
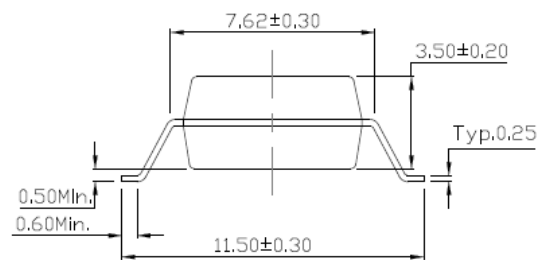
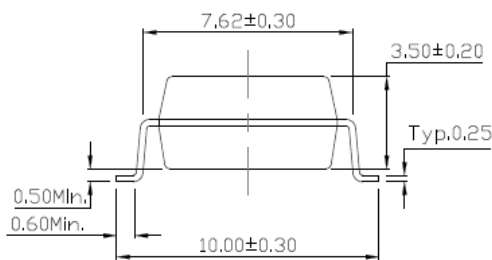
### Surface Mount Lead Forming



### Forming Option *Dimensions in mm unless otherwise stated*

S Type

SM Type







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## Marking Information



### Note:

- CT : Denotes “CT Micro”
- 480 : Part Number
- V : VDE Safety Mark Option (Blank or V)
- Y : One Digit Year Code
- WW : Two Digit Work Week
- K : Manufacturing Code

## Ordering Information

### CTS480(V)(Y)(Z)

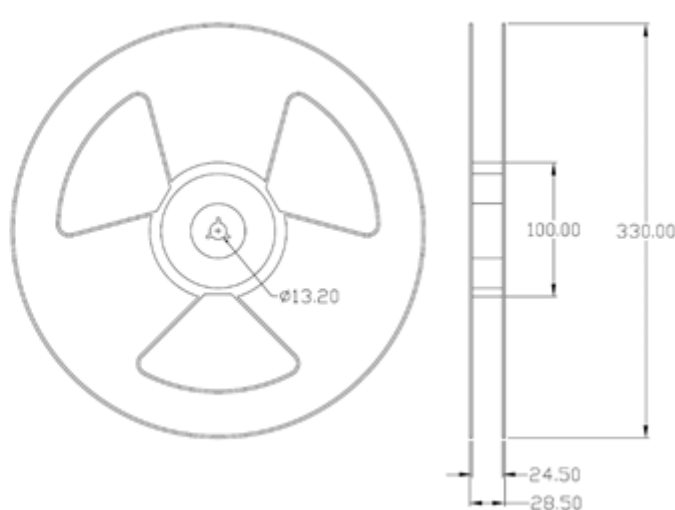
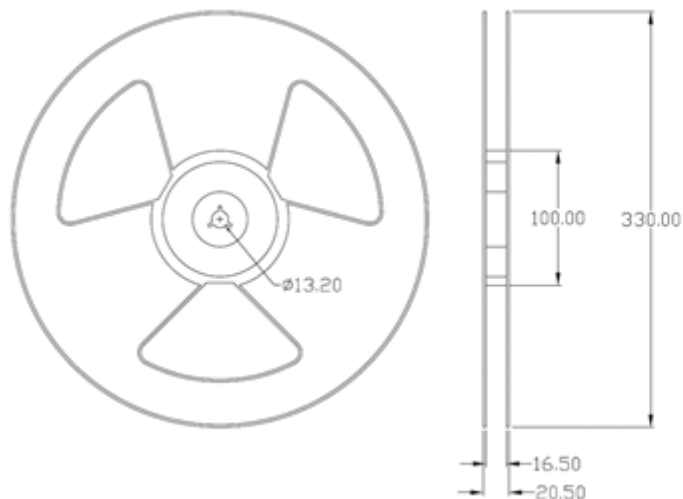
- CT = Denotes “CT Micro”
- S480 = Part Number
- V = VDE Safety Mark Option (Blank or V)
- Y = Lead Form Option (S or SM)
- Z = Tape and Reel Option (T1 or T2)

Option	Description	Quantity
T1	Surface Mount Lead Forming with Option 1 Taping	1500 Units/Reel
T2	Surface Mount Lead Forming with Option 2 Taping	1500 Units/Reel
M(T1)	Surface Mount (Gullwing) Lead Forming with Option 1 Taping	1500 Units/Reel
M(T2)	Surface Mount (Gullwing) Lead Forming with Option 2 Taping	1500 Units/Reel

## Reel Dimension *All dimensions are in mm, unless otherwise stated*

### Option S(T1/T2)

### Option M(T1/T2)



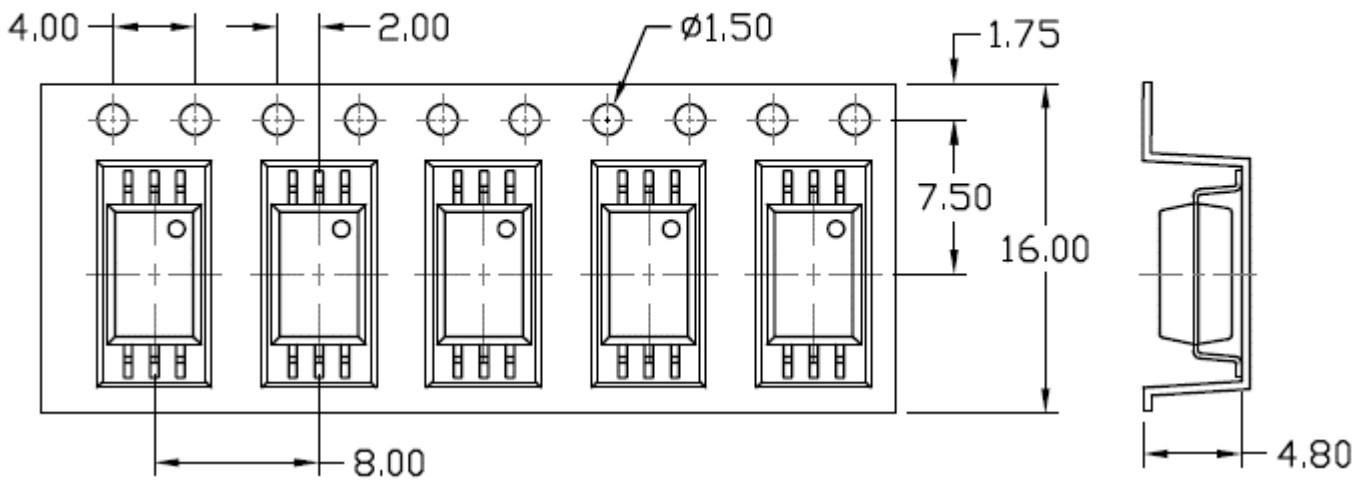


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## Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

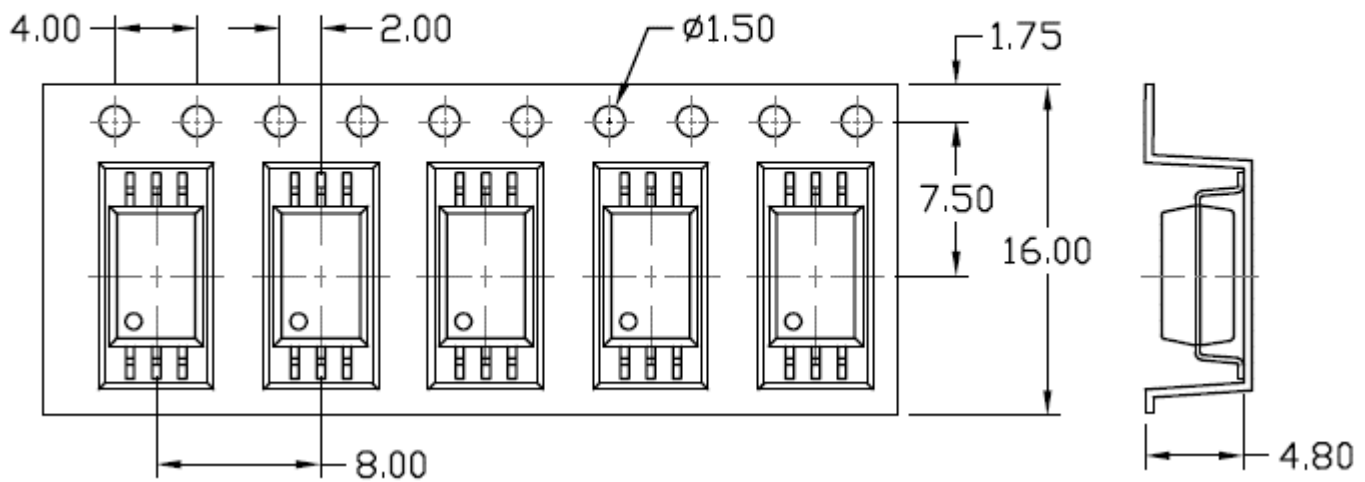
### Option S(T1)

Input Direction →



### Option S(T2)

Input Direction →

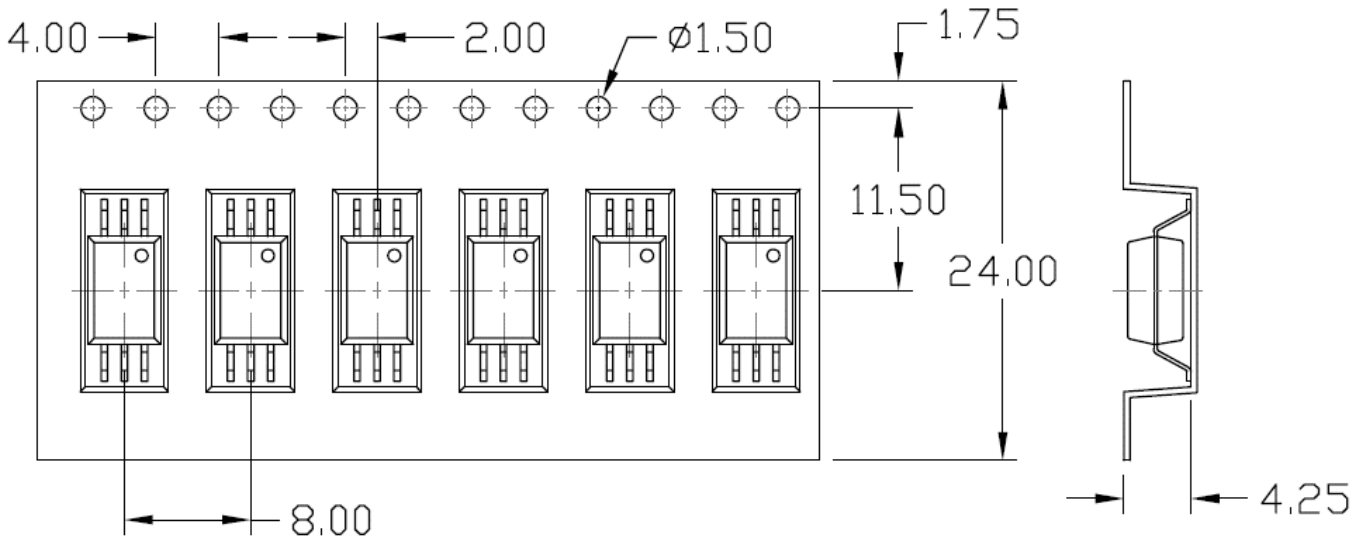




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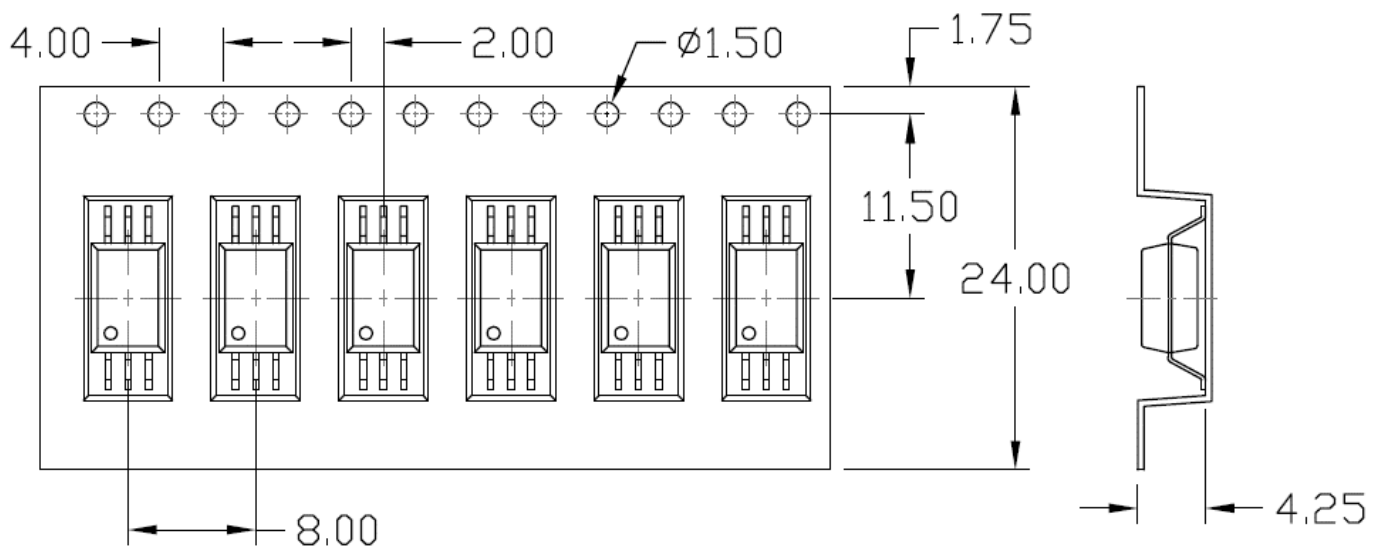
## Option SM(T1)

Input Direction



## Option SM(T2)

Input Direction





## High CMR Intelligent Power Module and Gate Drive Interface Optocoupler

### Solderability spec (Follow the JEDEC standard JESD22-B102)

Reflow Soldering: Immersed surface, other than the end of pin as cut-surface, must be covered by solder.

Solder-Bath: More than 95% of the electrode must be covered with solder.

### Wave soldering (Follow the JEDEC standard JESD22-A111)

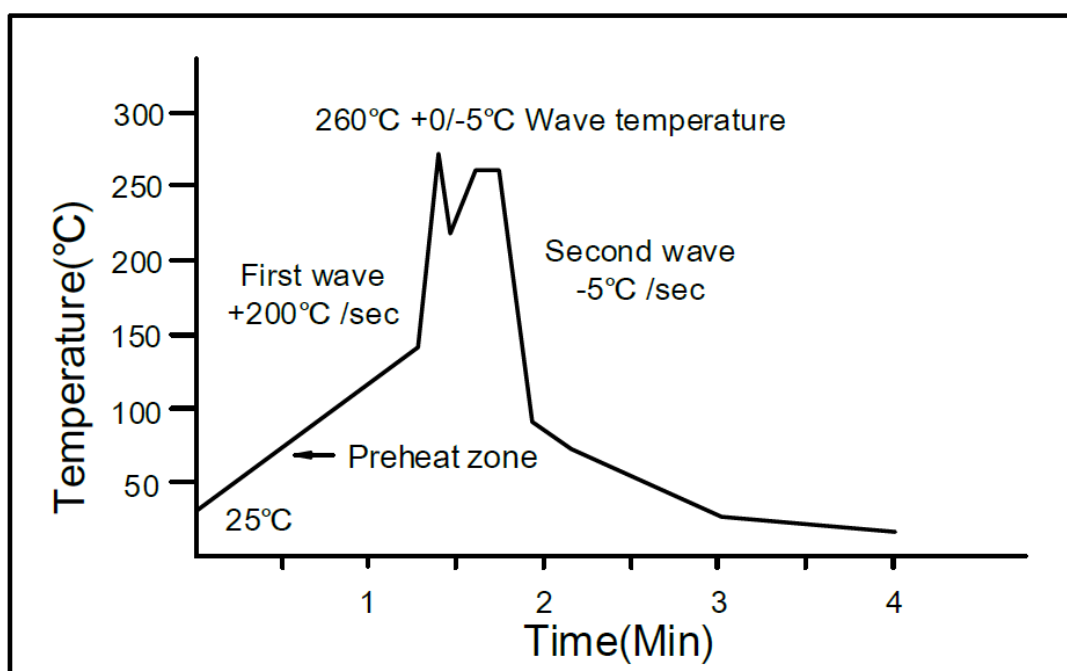
One time soldering is recommended within the condition of temperature.

Temperature:  $260 \pm 0/-5^\circ\text{C}$ .

Time: 10 sec.

Preheat temperature: 25 to  $140^\circ\text{C}$ .

Preheat time: 30 to 80 sec.



### Iron soldering (Follow the standard MIL-STD 202G, Method 210F)

Allow single lead soldering in every single process.

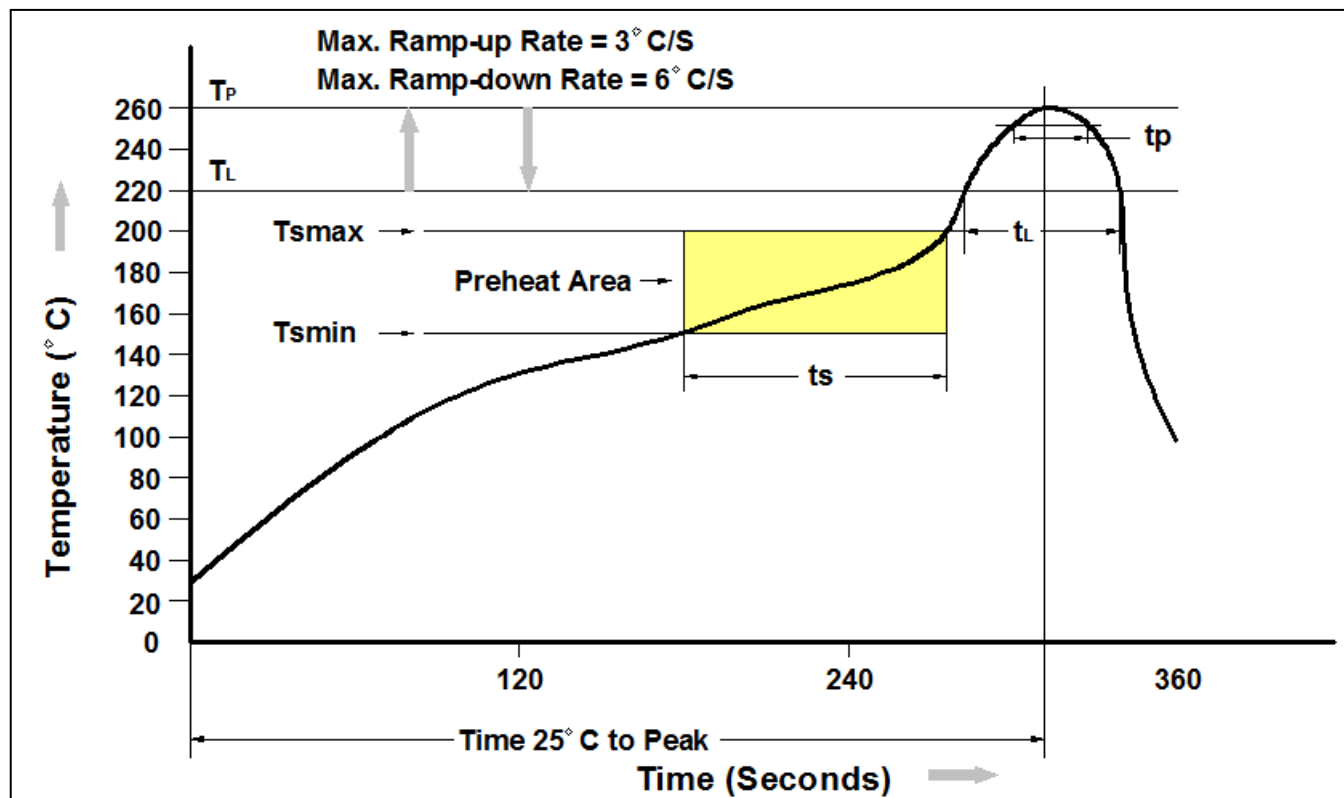
One time soldering is recommended. Temperature:  $350 \pm 10^\circ\text{C}$

Time: 5 sec max.



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## Reflow Profile (Follow the JEDEC standard J-STD-020)



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	150°C
Temperature Max. (T <sub>smax</sub> )	200°C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.*